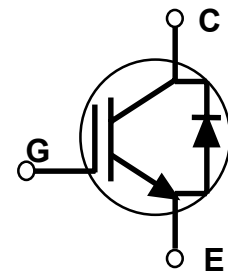
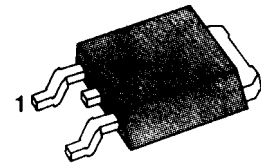


FEATURES

- * High Speed Switching
- * Low Saturation Voltage
: $V_{CE(sat)} = 1.95\text{ V}$ (@ $I_C = 12\text{ A}$)
- * High Input Impedance
- * CO-PAK, IGBT with FRD
: $T_{rr} = 42\text{ nS}$ (typ.)

APPLICATIONS

- * AC & DC Motor controls
- * General Purpose Inverters
- * Robotics , Servo Controls
- * Power Supply
- * Lamp Ballast

D²-PAK**ABSOLUTE MAXIMUM RATINGS**

Symbol	Characteristics	Rating	Units
V_{CES}	Collector-Emitter Voltage	600	V
V_{GES}	Gate-Emitter Voltage	± 20	V
I_C	Collector Current @ $T_c = 25^\circ\text{C}$	23	A
	Collector Current @ $T_c = 100^\circ\text{C}$	12	A
$I_{CM(1)}$	Pulsed Collector Current	92	A
I_F	Diode Continuous Forward Current @ $T_c = 100^\circ\text{C}$	12	A
I_{FM}	Diode Maximum Forward Current	92	A
P_D	Maximum Power Dissipation @ $T_c = 25^\circ\text{C}$	100	W
	Maximum Power Dissipation @ $T_c = 100^\circ\text{C}$	40	W
T_j	Operating Junction Temperature	$-55 \sim 150$	$^\circ\text{C}$
T_{stg}	Storage Temperature Range	$-55 \sim 150$	$^\circ\text{C}$
TL	Maximum Lead Temp. For Soldering	300	$^\circ\text{C}$
	Purposes, $\frac{1}{8}$ " from case for 5 seconds		

Notes:(1) Repetitive rating : Pulse width limited by max. junction temperature

ELECTRICAL CHARACTERISTICS (IGBT PART)
(T_c=25°C, Unless Otherwise Specified)

Symbol	Characteristics	Test Conditions	Min	Typ	Max	Units
BV _{CES}	C - E Breakdown Voltage	V _{GE} = 0V , I _C = 250μA	600	-	-	V
$\Delta V_{CES} / \Delta T_J$	Temperature Coeff. of Breakdown Voltage	V _{GE} = 0V , I _C = 1mA	-	0.6	-	V/°C
V _{GE(th)}	G - E threshold voltage	I _C = 12mA , V _{CE} = V _{GE}	4.0	5.5	7.5	V
I _{CES}	Collector cutoff Current	V _{CE} = V _{CES} , V _{GE} = 0V	-	-	250	uA
I _{GES}	G - E leakage Current	V _{GE} = V _{GES} , V _{CE} = 0V	-	-	100	nA
V _{CE(sat)}	Collector to Emitter saturation voltage	I _C =12A, V _{GE} = 15V	-	1.95	2.6	V
		I _C =23A, V _{GE} = 15V	-	2.6	-	V
Cies	Input capacitance	V _{GE} = 0V , f = 1MHz V _{CE} = 30V	-	720	-	pF
Coes	Output capacitance		-	103	-	pF
Cres	Reverse transfer capacitance		-	26	-	pF
td(on)	Turn on delay time	V _{CC} = 300V , I _C = 12A V _{GE} = 15V R _G = 23 Ω Inductive Load	-	12	-	ns
tr	Turn on rise time		-	20	-	ns
td(off)	Turn off delay time		-	55	85	ns
tf	Turn off fall time		-	100	220	ns
Eon	Turn on Switching Loss		-	0.11	-	mJ
Eoff	Turn off Switching Loss		-	0.19	-	mJ
Ets	Total Switching Loss		-	0.3	0.5	mJ
Qg	Total Gate Charge	V _{CC} = 300V	-	48	72	nC
Qge	Gate-Emitter Charge	V _{GE} = 15V	-	11	16	nC
Qgc	Gate-Collector Charge	I _C = 12A	-	14	21	nC
Le	Internal Emitter Inductance	Measured 5mm from PKG	-	14	-	nH

SGW23N60UFD

N-CHANNEL IGBT

ELECTRICAL CHARACTERISTICS (DIODE PART)

(T_c=25°C, Unless Otherwise Specified)

Symbol	Characteristics	Test Conditions		Min	Typ	Max	Units
VFM	Diode Forward Voltage	IF=12A	Tc =25 °C	-	1.4	1.7	V
			Tc =100 °C	-	1.3	-	
Trr	Diode Reverse Recovery Time	IF=12A, VR=200V -di/dt=200A/uS	Tc =25 °C	-	42	60	nS
			Tc =100 °C	-	80	-	
Irr	Diode Peak Reverse Recovery Current		Tc =25 °C	-	3.5	6.0	A
			Tc =100 °C	-	5.6	-	
Qrr	Diode Reverse Recovery Charge		Tc =25 °C	-	80	180	nC
			Tc =100 °C	-	220	-	

THERMAL RESISTANCE

Symbol	Characteristics	Min	Typ	Max	Units
R _{θJC}	Junction-to-Case (IGBT)	-	-	1.2	°C/W
R _{θJC}	Junction-to-Case (DIODE)	-	-	2.5	°C/W
R _{θJA}	Junction-to-Ambient (PCB mount)	-	-	40	°C/W

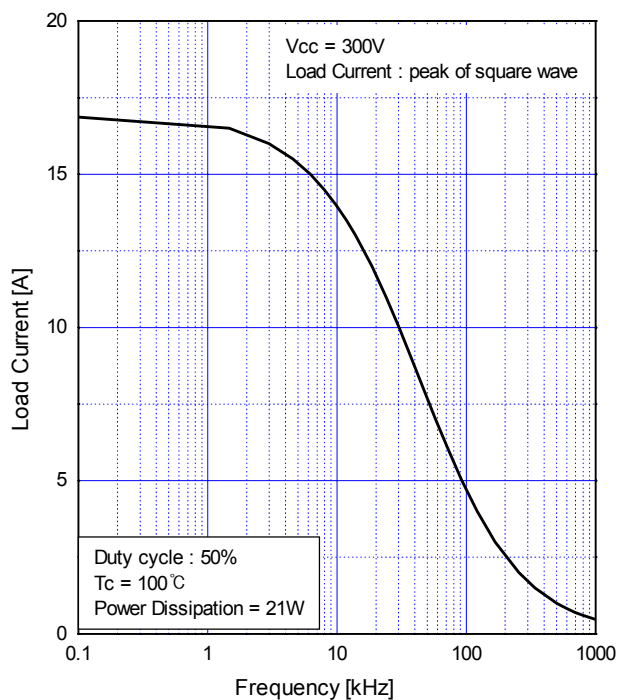


Fig.1 Typical Load Current vs. Frequency

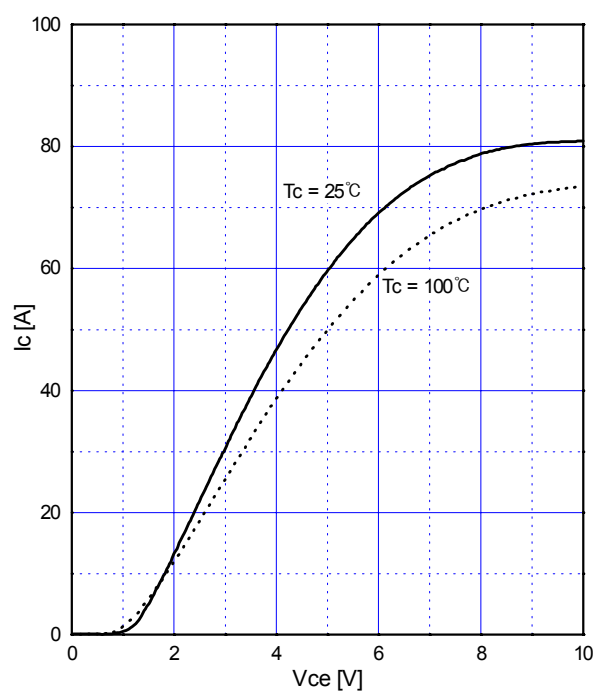


Fig.2 Typical Output Characteristics

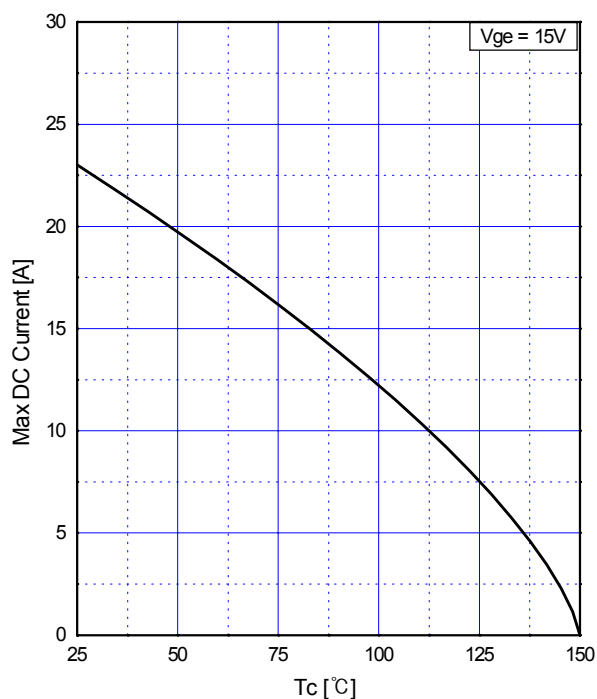


Fig.3 Maximum Collector Current vs. Case Temperature

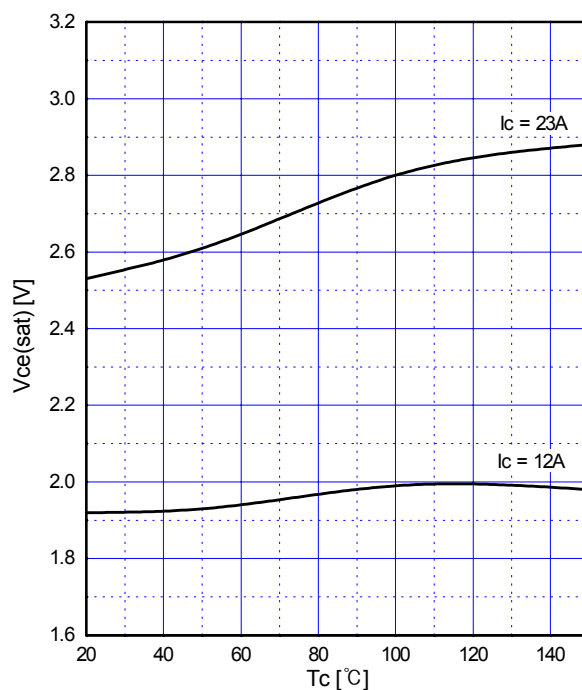


Fig.4 Collector to Emitter Voltage vs. Case Temperature

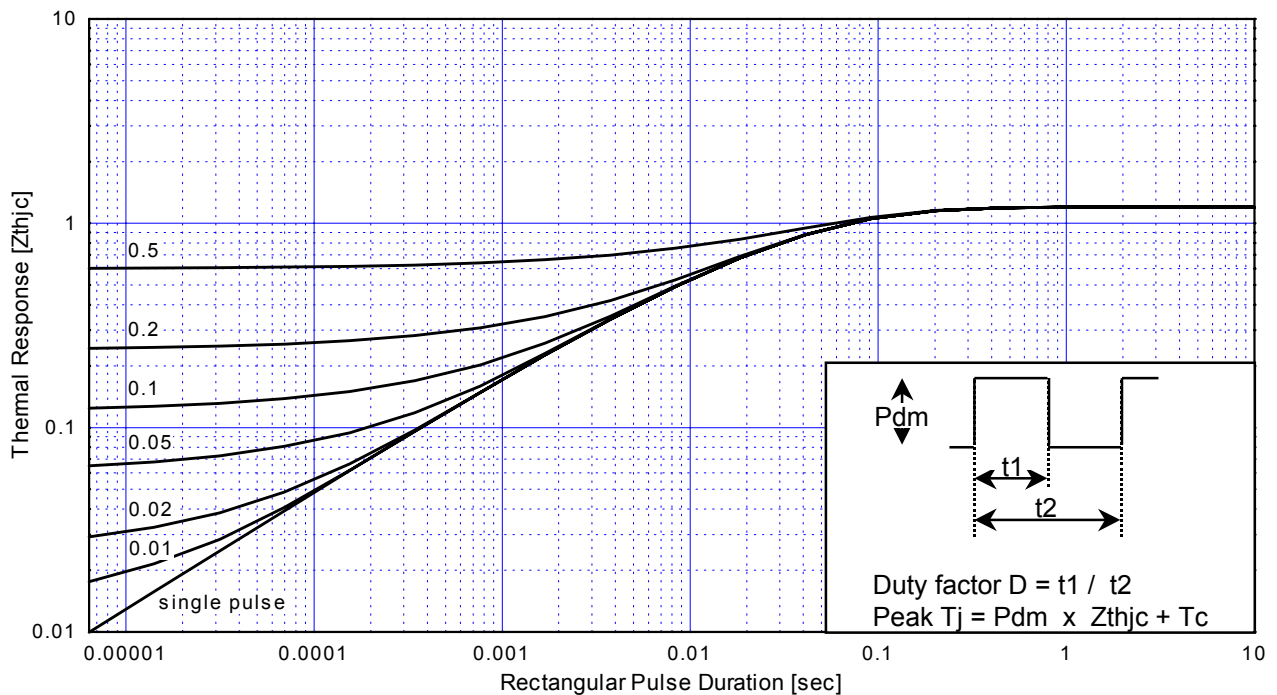


Fig.5 Maximum Effective Transient Thermal Impedance, Junction to Case

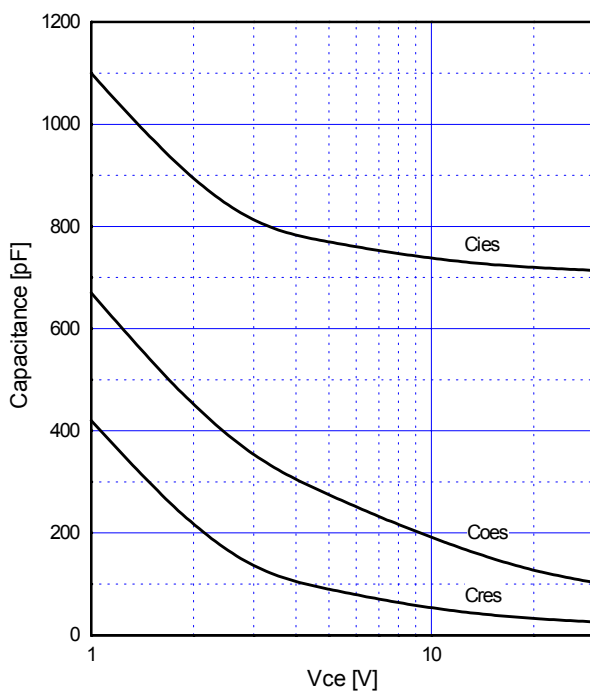


Fig.6 Typical Capacitance vs. Collector to Emitter Voltage

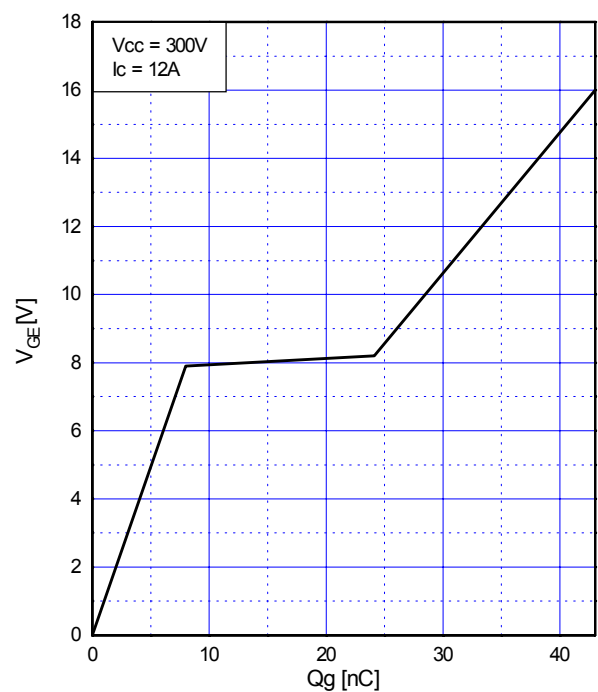


Fig.7 Typical Gate Charge vs. Gate to Emitter Voltage

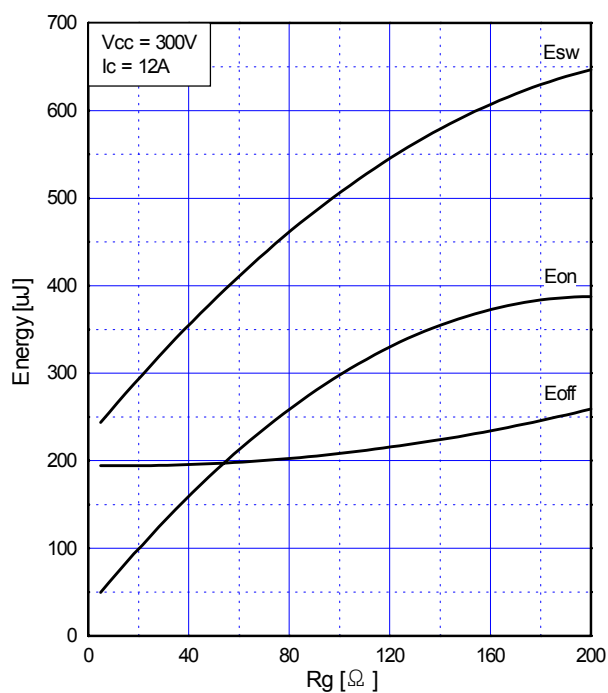


Fig.8 Typical Switching Loss vs. Gate Resistance

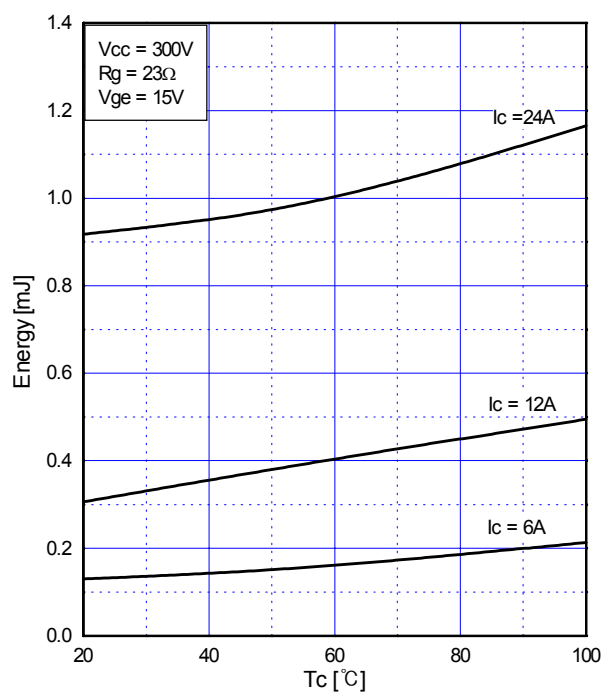


Fig.9 Typical Switching Loss vs. Case Temperature

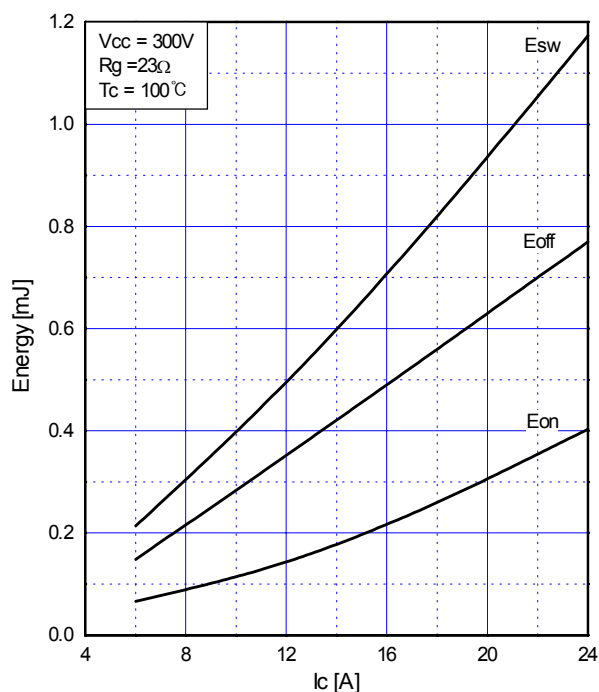


Fig.10 Typical Switching loss vs. Collector to Emitter Current

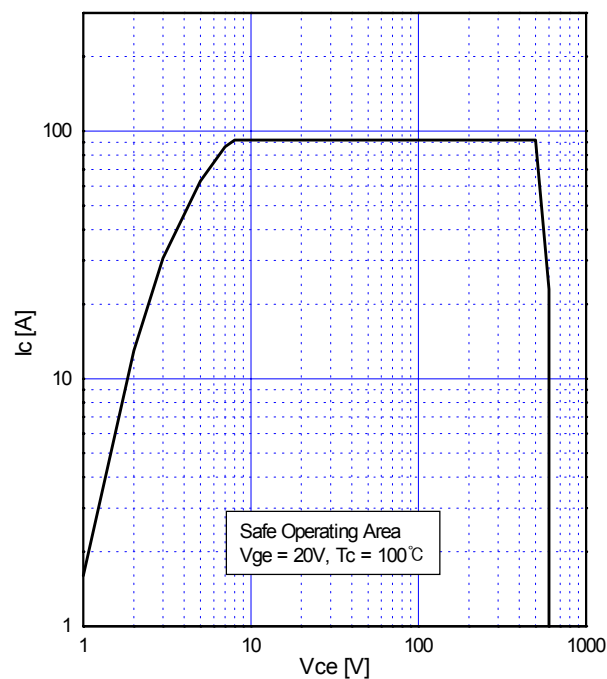


Fig.11 Turn-off SOA

